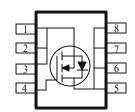
### N-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

PRODUCT SUMMARY				
$V_{DS}(V)$	$r_{DS(on)} m(\Omega)$	$I_{D}(A)$		
30	$6 @ V_{GS} = 10V$	18.6		
	$8 @ V_{GS} = 4.5V$	16.1		

- $\begin{array}{ll} \bullet & \quad Low \; r_{DS(on)} \; provides \; higher \; efficiency \; and \\ extends \; battery \; life \\ \end{array}$
- Low thermal impedance copper leadframe SOIC-8 saves board space
- Fast switching speed
- High performance trench technology





ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)					
Parameter			Maximum	Units	
Drain-Source Voltage			30	V	
Gate-Source Voltage			20	V	
Continuous Drain Current <sup>a</sup>	$T_A=25^{\circ}C$	T	18.6		
Continuous Drain Current	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	П	15.7	A	
Pulsed Drain Current <sup>b</sup>			60		
Continuous Source Current (Diode Conduction) <sup>a</sup>		$I_S$	2.9	Α	
D D a	$T_A=25^{\circ}C$	$D_{-}$	3.1	W	
Power Dissipation <sup>a</sup>	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	Гр	2.2		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Maximum	Units			
	t <= 10 sec	D	40	°C/W		
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	$R_{ heta JA}$	80	°C/W		

1

#### Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Parameter	Symbol	Took Conditions		Limits		Unit	
r ar ameter	Symbol	<b>Test Conditions</b>	Min	Тур	Max		
Static							
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	1		3	V	
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = 20 \text{ V}$			100	nA	
Zero Gate Voltage Drain Current	$I_{ m DSS}$	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Zero Gate Voltage Drain Current	1DSS	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			5	uA	
On-State Drain Current <sup>A</sup>	$I_{D(on)}$	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			A	
Drain-Source On-Resistance <sup>A</sup>	r <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_D = 18.6 \text{ A}$			6	mΩ	
Drain-Source On-Resistance		$V_{GS} = 4.5 \text{ V}, I_D = 16.1 \text{ A}$			8	1112.2	
Forward Tranconductance <sup>A</sup>	$g_{\mathrm{fs}}$	$V_{DS} = 15 \text{ V}, I_D = 18.6 \text{ A}$		90		S	
Diode Forward Voltage	$V_{\mathrm{SD}}$	$I_S = 2.3 \text{ A}, V_{GS} = 0 \text{ V}$		0.7		V	
Dynamic <sup>b</sup>							
Total Gate Charge	$Q_{g}$	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$		25			
Gate-Source Charge	$Q_{gs}$	$I_{DS} = 13 \text{ v}, \text{ v}_{GS} = 4.3 \text{ v},$ $I_{D} = 18.6 \text{ A}$		6		nC	
Gate-Drain Charge	$Q_{gd}$	$I_{\rm D} = 16.0~{\rm A}$		9		1	
Turn-On Delay Time	$t_{d(on)}$			20			
Rise Time	$t_{\rm r}$	$V_{DD} = 15 \text{ V}, R_L = 6 \Omega, ID = 1 \text{ A},$		13		nS	
Turn-Off Delay Time	$t_{d(off)}$	VGEN = 10 V		82		113	
Fall-Time	$t_{\rm f}$			43			

#### Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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## Typical Electrical Characteristics (N-Channel)

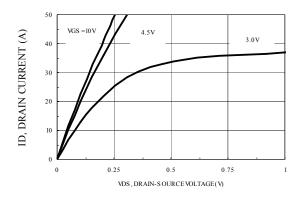


Figure 1. Output Characteristics

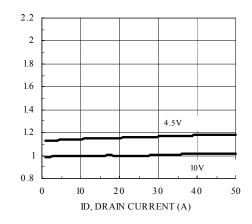


Figure 3. On-Resistance vs. Drain Current

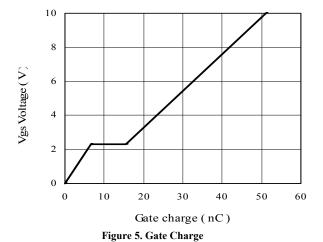


Figure 2. Transfer Characteristics

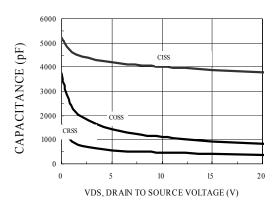


Figure 4. Capacitance

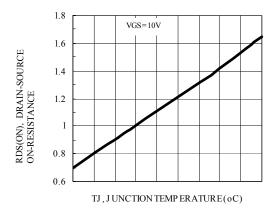


Figure 6. On-Resistance vs. Junction Temperature

RDS(ON), DRAIN-SOURCE ON-RESISTANCE

### Typical Electrical Characteristics (N-Channel)

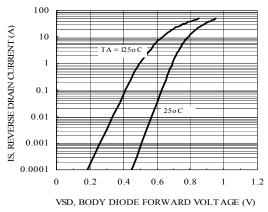


Figure 7. Source-Drain Diode Forward Voltage

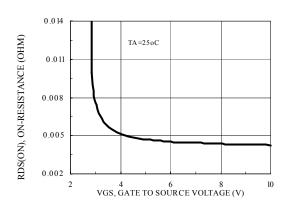


Figure 8. On-Resistance vs. Gate-to-Source Voltage

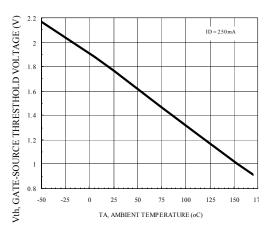


Figure 9. Threshold Voltage

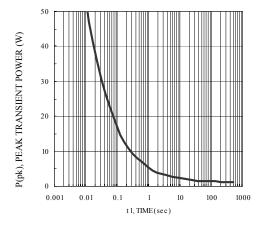
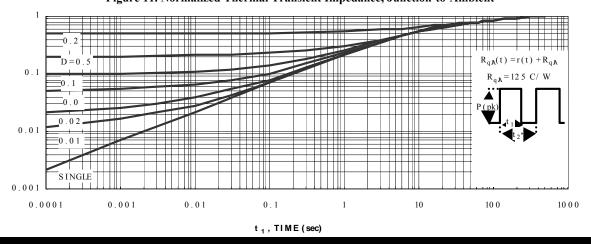


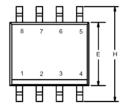
Figure 10. Single Pulse Power

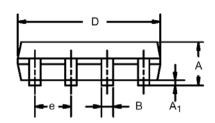
Figure 11. Normalized Thermal Transient Impedance, Junction-to-Ambient



# Package Information

SO-8: 8LEAD





	MILLIN	IETERS	INCHES		
Dim	Min	Max	Min	Max	
Α	1.35	1.75	0.053	0.069	
A <sub>1</sub>	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
E	3.80	4.00	0.150	0.157	
е	1.27 BSC		0.050 BSC		
Н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	

